

SN74CBTD3305C

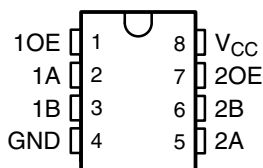
DUAL FET BUS SWITCH WITH LEVEL SHIFTING

5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

SCDS126A – SEPTEMBER 2003 – REVISED OCTOBER 2003

- Undershoot Protection for Off-Isolation on A and B Ports Up To –2 V
- Integrated Diode to V_{CC} Provides 5-V Input Down To 3.3-V Output Level Shift
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance (r_{on}) Characteristics ($r_{on} = 3\ \Omega$ Typical)
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion ($C_{io(OFF)} = 5\text{ pF}$ Typical)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- V_{CC} Operating Range From 4.5 V to 5.5 V
- Data I/Os Support 0 to 5-V Signaling Levels (0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, 5-V)
- Control Inputs Can be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: USB Interface, Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating

D OR PW PACKAGE
(TOP VIEW)



description/ordering information

The SN74CBTD3305C is a high-speed TTL-compatible FET bus switch with low ON-state resistance (r_{on}), allowing for minimal propagation delay. This device features an integrated diode in series with V_{CC} to provide level shifting for 5-V input down to 3.3-V output levels. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBTD3305C provides protection for undershoot up to –2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBTD3305C is organized as two 1-bit bus switches with separate output-enable (1OE, 2OE) inputs. It can be used as two 1-bit bus switches or as one 2-bit bus switch. When OE is high, the associated 1-bit bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When OE is low, the associated 1-bit bus switch is OFF, and a high-impedance state exists between the A and B ports.

ORDERING INFORMATION

| T_A | PACKAGE† | | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|---------------|------------|---------------|-----------------------|------------------|
| –40°C to 85°C | SOIC – D | Tube | SN74CBTD3305CD | CC305C |
| | | Tape and reel | SN74CBTD3305CDR | |
| | TSSOP – PW | Tube | SN74CBTD3305CPW | CC305C |
| | | Tape and reel | SN74CBTD3305CPWR | |

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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DUAL FET BUS SWITCH WITH LEVEL SHIFTING

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description/ordering information (continued)

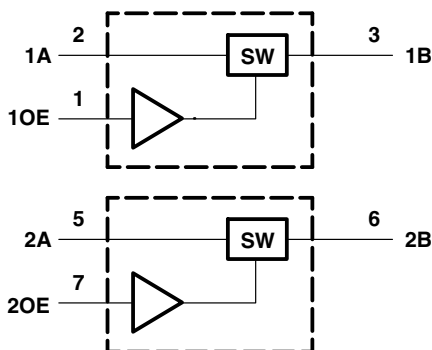
This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

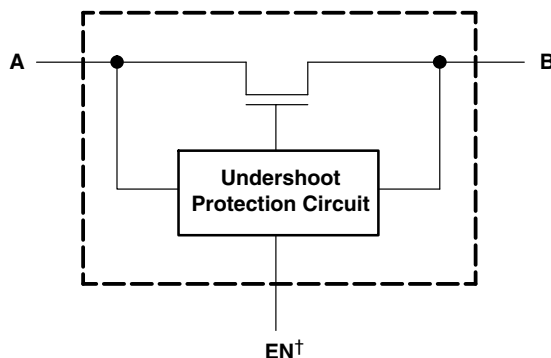
FUNCTION TABLE
(each bus switch)

| INPUT OE | INPUT/OUTPUT A | FUNCTION |
|-------------|-------------------|-----------------|
| H | B | A port = B port |
| L | Z | Disconnect |

logic diagram (positive logic)



simplified schematic, each FET switch (SW)



† EN is the internal enable signal applied to the switch.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

| | |
|--|----------------|
| Supply voltage range, V_{CC} | –0.5 V to 7 V |
| Control input voltage range, V_{IN} (see Notes 1 and 2) | –0.5 V to 7 V |
| Switch I/O voltage range, $V_{I/O}$ (see Notes 1, 2, and 3) | –0.5 V to 7 V |
| Control input clamp current, I_{IK} ($V_{IN} < 0$) | –50 mA |
| I/O port clamp current, $I_{I/OK}$ ($V_{I/O} < 0$) | –50 mA |
| ON-state switch current, $I_{I/O}$ (see Note 4) | ±128 mA |
| Continuous current through V_{CC} or GND terminals | ±100 mA |
| Package thermal impedance, θ_{JA} (see Note 5): D package | 97°C/W |
| PW package | 149°C/W |
| Storage temperature range, T_{stg} | –65°C to 150°C |

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltages are with respect to ground unless otherwise specified.
 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 3. V_I and V_O are used to denote specific conditions for $V_{I/O}$.
 4. I_I and I_O are used to denote specific conditions for $I_{I/O}$.
 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Notes 6 and 7)

| | MIN | MAX | UNIT |
|---|-----|-----|------|
| V_{CC} Supply voltage | 4.5 | 5.5 | V |
| V_{IH} High-level control input voltage | 2 | 5.5 | V |
| V_{IL} Low-level control input voltage | 0 | 0.8 | V |
| $V_{I/O}$ Data input/output voltage | 0 | 5.5 | V |
| T_A Operating free-air temperature | –40 | 85 | °C |

- NOTES:
6. All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
 7. In applications with fast edge rates, multiple outputs switching, and operating at high frequencies, the output may have little or no level-shifting effect.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | | MIN | TYP† | MAX | UNIT | |
|-----------------------|----------------|------------------------------|--|-------------------------|-----|------|------|------|---|
| V _{IK} | Control inputs | V _{CC} = 4.5 V, | I _{IN} = −18 mA | | | | −1.8 | V | |
| V _{IKU} | Data inputs | V _{CC} = 5 V, | 0 mA > I _I ≥ −50 mA, V _{IN} = V _{CC} or GND, Switch OFF | | | | −2 | V | |
| V _{OH} | | See Figures 4 and 5 | | | | | | | |
| I _{IN} | Control inputs | V _{CC} = 5.5 V, | V _{IN} = V _{CC} or GND | | | | ±1 | μA | |
| I _{OZ} ‡ | | V _{CC} = 5.5 V, | V _O = 0 to 5.5 V, Switch OFF, V _I = 0, V _{IN} = V _{CC} or GND | | | | ±10 | μA | |
| I _{off} | | V _{CC} = 0, | V _O = 0 to 5.5 V, V _I = 0 | | | | 10 | μA | |
| I _{CC} | | V _{CC} = 5.5 V, | I _{I/O} = 0, V _{IN} = V _{CC} or GND, Switch ON or OFF | | | | 1.5 | mA | |
| ΔI _{CC} § | Control inputs | V _{CC} = 5.5 V, | One input at 3.4 V, Other inputs at V _{CC} or GND | | | | 2.5 | mA | |
| C _{in} | Control inputs | V _{IN} = 3 V or 0 | | | | | 3.5 | pF | |
| C _{io} (OFF) | | V _{I/O} = 3 V or 0, | Switch OFF, V _{IN} = V _{CC} or GND | | | | 5 | pF | |
| C _{io} (ON) | | V _{I/O} = 3 V or 0, | Switch ON, V _{IN} = V _{CC} or GND | | | | 12.5 | pF | |
| r _{on} | | V _{CC} = 4.5 V | V _I = 0 | I _O = 64 mA | | | 3 | 6 | Ω |
| | | | | I _O = 30 mA | | | 3 | 6 | |
| | | | V _I = 2.4 V, | I _O = −15 mA | | | | 8 | |

V_{IN} and I_{IN} refer to control inputs. V_I , V_O , I_I , and I_O refer to data pins.

† All typical values are at $V_{CC} = 5\text{ V}$ (unless otherwise noted), $T_A = 25^\circ\text{C}$.

‡ For I/O ports, the parameter I_{OZ} includes the input leakage current.

§ This is the increase in supply current for each input that is at the specified voltage level, rather than V_{CC} or GND.

∥ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC} = 5\text{ V}$ $\pm 0.5\text{ V}$ | | UNIT |
|-------------|--------------|-------------|---|------|------|
| | | | MIN | MAX | |
| $t_{pd}^\#$ | A or B | B or A | | 0.15 | ns |
| t_{en} | OE | A or B | 1.5 | 4.7 | ns |
| t_{dis} | OE | A or B | 1.5 | 5.3 | ns |

The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

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undershoot characteristics (see Figures 1 and 2)

| PARAMETER | TEST CONDITIONS | MIN | TYP† | MAX | UNIT |
|------------|--|-----|----------------|-----|------|
| V_{OUTU} | $V_{CC} = 5.5\text{ V}$, Switch OFF, $V_{IN} = V_{CC}$ or GND | 2 | $V_{OH} - 0.3$ | | V |

† All typical values are at $V_{CC} = 5\text{ V}$ (unless otherwise noted), $T_A = 25^\circ\text{C}$.

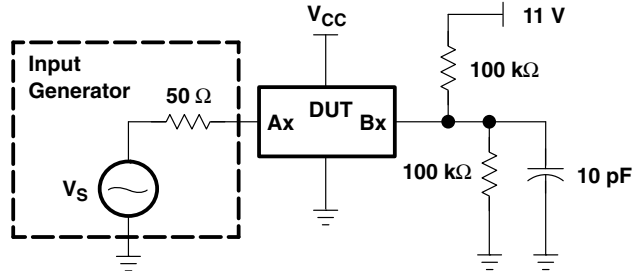


Figure 1. Device Test Setup

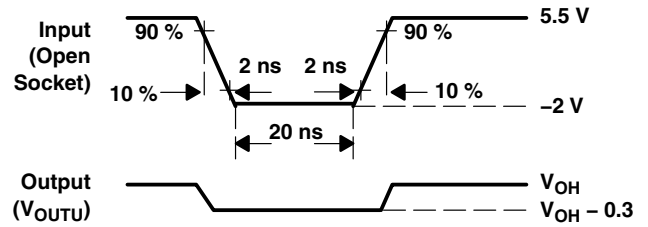


Figure 2. Transient Input Voltage (V_i) and Output Voltage (V_{OUTU}) Waveforms (Switch OFF)

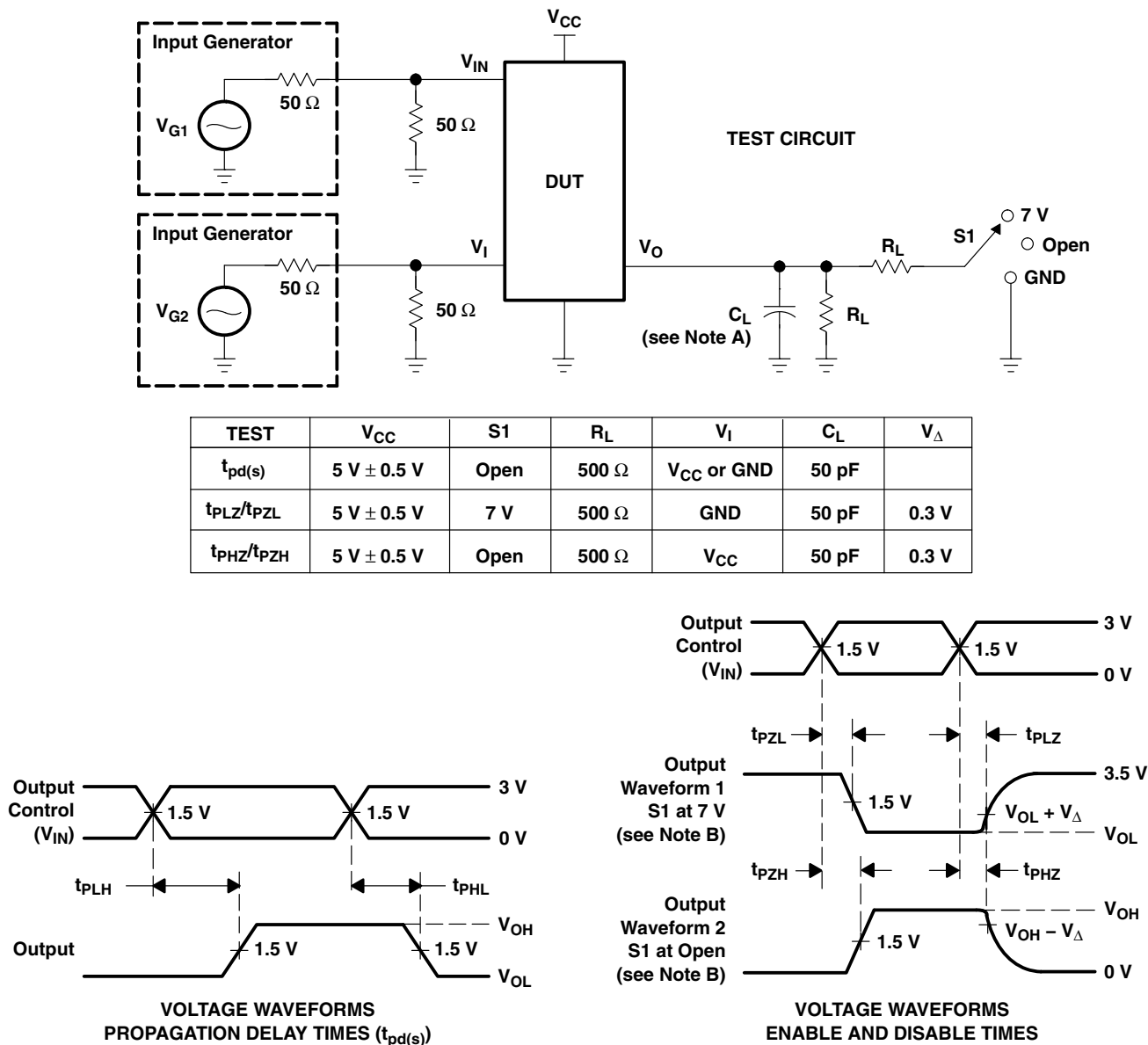
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PARAMETER MEASUREMENT INFORMATION FOR LEVEL SHIFTER



- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 2.5\text{ ns}$, $t_f \leq 2.5\text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as $t_{pd(s)}$. The t_{pd} propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
 - All parameters and waveforms are not applicable to all devices.

Figure 3. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

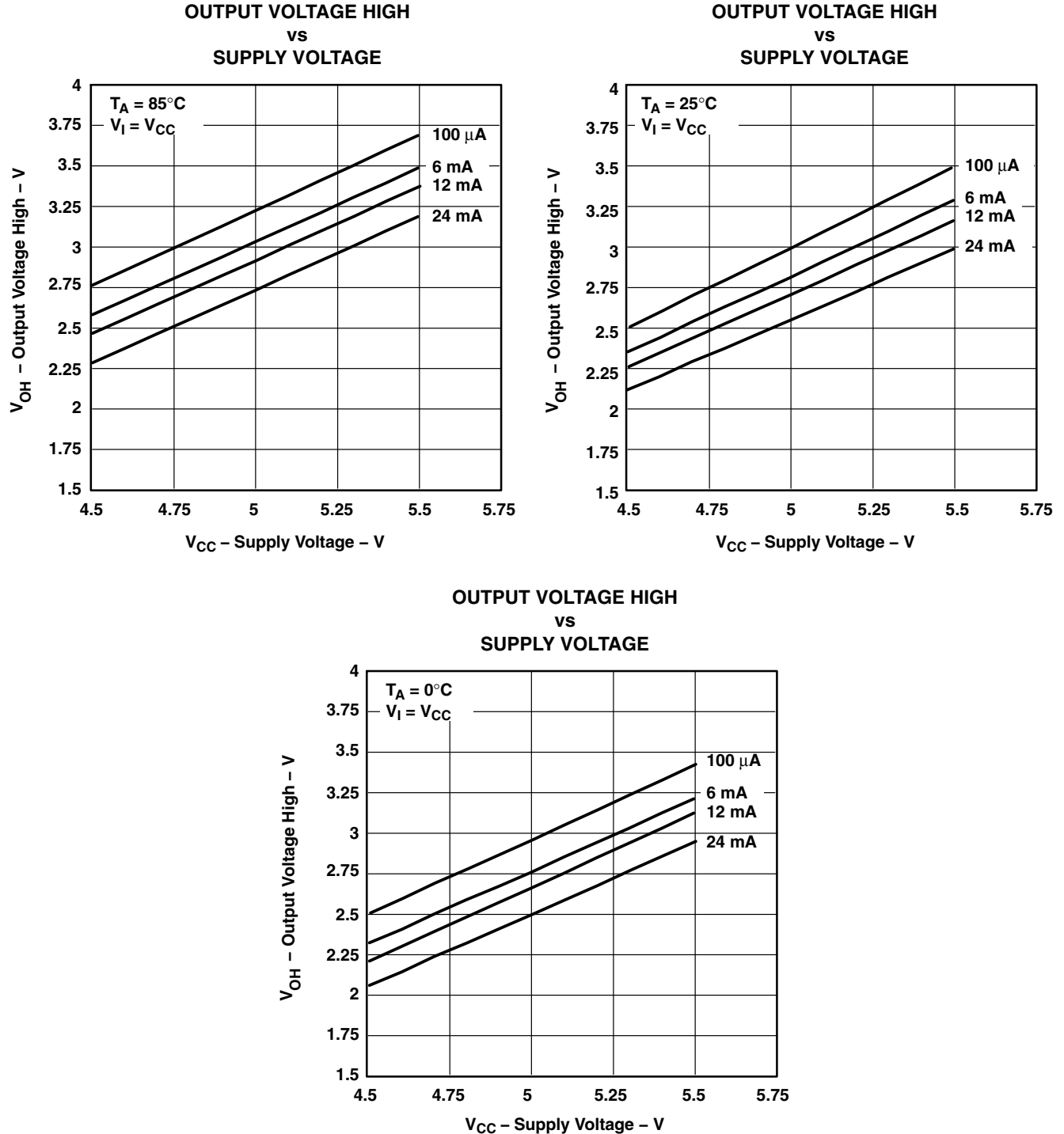


Figure 4. V_{OH} Values

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TYPICAL CHARACTERISTICS (continued)

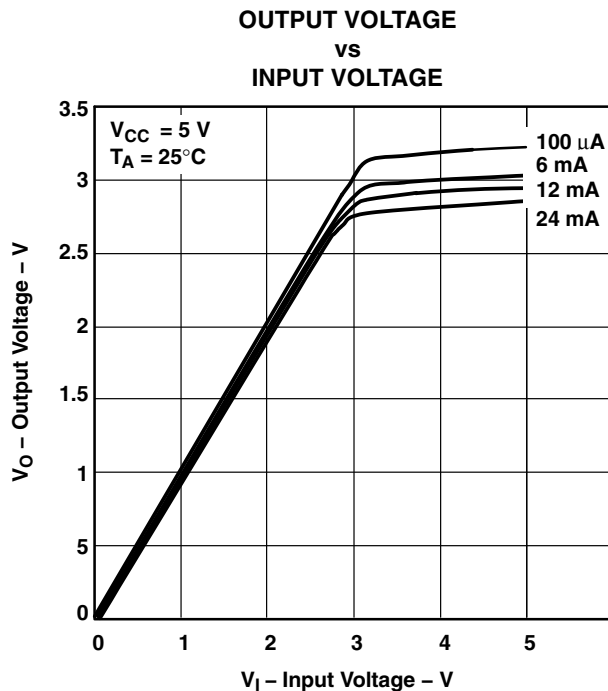


Figure 5. Data Output Voltage vs Data Input Voltage

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|--------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| SN74CBTD3305CD | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CC305C | Samples |
| SN74CBTD3305CDR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CC305C | Samples |
| SN74CBTD3305CPWR | ACTIVE | TSSOP | PW | 8 | 2000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 85 | CC305C | Samples |
| SN74CBTD3305CPWRG3 | PREVIEW | TSSOP | PW | 8 | 2000 | TBD | Call TI | Call TI | -40 to 85 | | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| SN74CBTD3305CDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN74CBTD3305CPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN74CBTD3305CPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74CBTD3305CDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| SN74CBTD3305CPWR | TSSOP | PW | 8 | 2000 | 364.0 | 364.0 | 27.0 |
| SN74CBTD3305CPWR | TSSOP | PW | 8 | 2000 | 367.0 | 367.0 | 35.0 |



D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

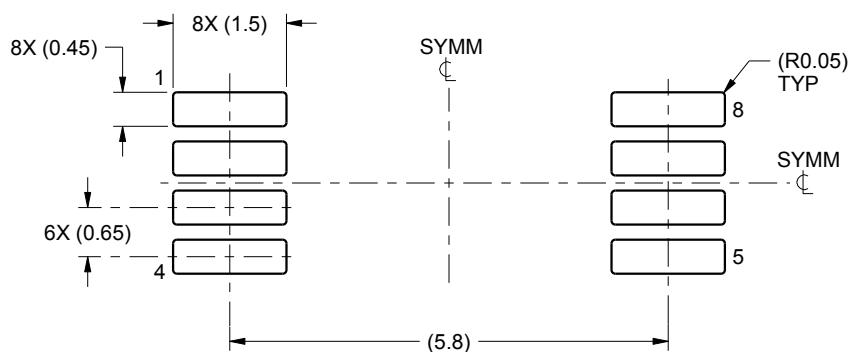
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221848/A 02/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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